

Extremely low capacitance bidirectional ESD protection diode . Rev. 1 — 12 March 2012 Product data sheet

1. **Product profile**

1.1 General description

Extremely low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a leadless ultra small SOD882 (DFN1006-2) Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients. The combination of extremely low capacitance, high ESD maximum rating and ultra small package makes the device ideal for high-speed data line protection.

1.2 Features and benefits

- Bidirectional ESD protection of one line ESD protection up to 8 kV
- Extremely low capacitance: $C_{d} = 0.49 \text{ pF}$
- Low clamping voltage: V_{CL} = 18 V
- Ultra low leakage current: I_{RM} = 1 nA

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- 10/100/1000 Mbit/s Ethernet
- USB, High-Definition Multimedia Interface (HDMI), FireWire

1.4 Quick reference data

- IEC 61000-4-2; level 4 (ESD)
- AEC-Q101 qualified
- Portable electronics
- SIM card protection
- High-speed data lines
- Communication systems

Table 1.	Quick reference data						
Symbol	Parameter Conditions Min Typ Max Unit						
Per devic	e						
V _{RWM}	reverse standoff voltage		-	-	5.5	V	
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	0.49	0.60	pF	



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2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	cathode (diode 1)		
2	cathode (diode 2)	1 2	1 2 sym045
		Transparent top view	

3. Ordering information

Table 3. Ordering	information		
Type number	Package		
	Name	Description	Version
PESD5V0X1BCL	DFN1006-2	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882

4. Marking

Table 4. Mar	king codes	
Type number		Marking code
PESD5V0X1BC	CL	11

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
I _{PPM}	rated peak pulse current	t _p = 8/20 μs	<u>[1]</u> _	1.7	А
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device stressed with ten non-repetitive current pulses (8/20 μ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321).

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Table 6.ESD maximum ratings

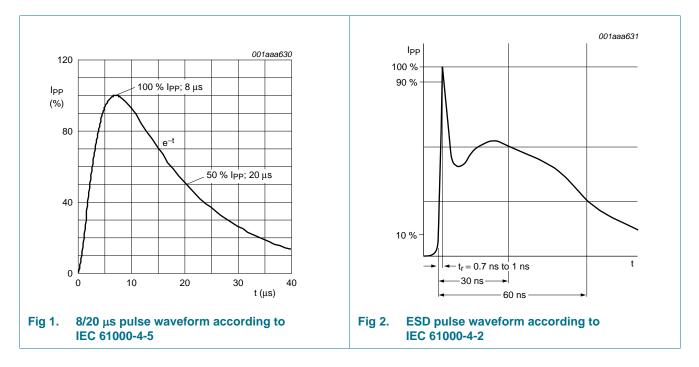
 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Parameter	Conditions	Min	Мах	Unit
e				
electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1]</u> _	8	kV
	machine model	-	400	V
	MIL-STD-883 (human body model)	-	10	kV
	e	electrostatic discharge voltage ielectrostatic discharge voltage (contact discharge) machine model MIL-STD-883	electrostatic discharge voltage IEC 61000-4-2 [1] - (contact discharge) machine model - MIL-STD-883 -	electrostatic discharge voltage IEC 61000-4-2 [1] - 8 (contact discharge) - 400 MIL-STD-883 - 10

[1] Device stressed with ten non-repetitive ESD pulses.

Table 7.	ESD s	standards	compliance
		, and a do	o o in pilano o

Conditions
> 8 kV (contact)
> 8 kV



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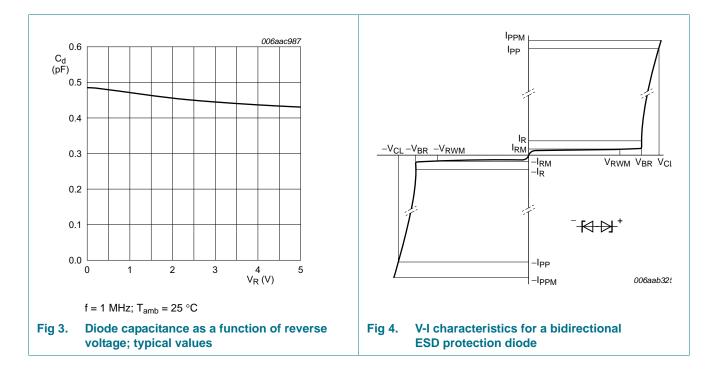
6. Characteristics

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Tamb = 20 0 unless otherwise specified.							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Per devi	ce						
V _{RWM}	reverse standoff voltage		-	-	5.5	V	
I _{RM}	reverse leakage current	$V_{RWM} = 5.5 V$	-	<1	10	nA	
V_{BR}	breakdown voltage	I _R = 10 mA	8.1	9.8	12.3	V	
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	0.49	0.60	pF	
V _{CL}	clamping voltage	I _{PPM} = 1.7 A	<u>[1]</u> _	-	18	V	
r _{dyn}	dynamic resistance	I _R = 10 A	[2] _	0.9	-	Ω	

[1] Device stressed with 8/20 μ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

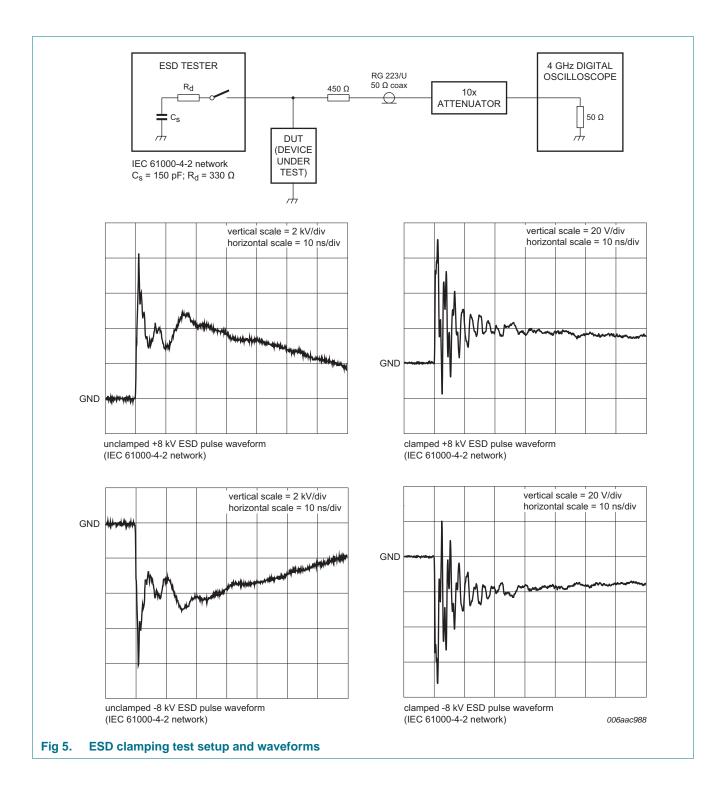
[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5-1-2008.



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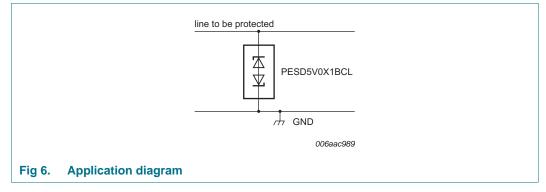


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7. Application information

PESD5V0X1BCL is designed for the protection of one bidirectional data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both, positive and negative with respect to ground.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

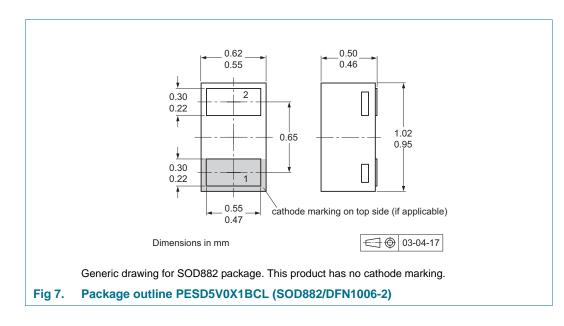
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 9. Packing methods

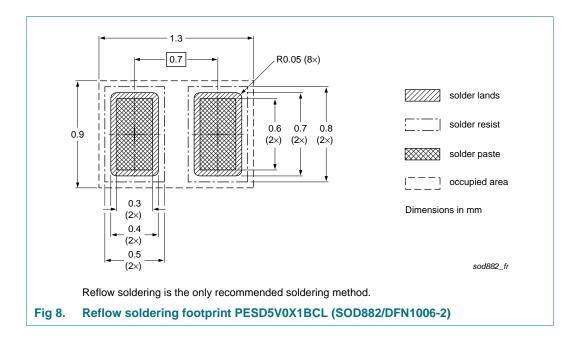
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
PESD5V0X1BCL	SOD882	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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11. Soldering



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12. Revision history

Table 10. Revision hist	Fable 10. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes				
PESD5V0X1BCL v.1	20120312	Product data sheet	-	-				

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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